

VT-701 Temperature Compensated Crystal Oscillator Previous Vectron Model VTC2





Vectron's VT-701 Temperature Compensated Crystal Oscillator (TCXO) is a quartz stabilized, clipped sine wave output, analog temperature compensated oscillator, operating off either a 3.3 or 5.0 volt supply in a hermetically sealed 5x7 ceramic package.

Features

- CMOS Output
- Output Frequencies to 27 MHz
- Fundamental Crystal Design
- Optional VCXO Function available
- Gold over nickel contact pads
- Hermetically Sealed Ceramic SMD package
- Product is compliant to RoHS directive and fully compatible with lead free assembly

- **Applications**
- FPGA's
- A/D's, D/A's
- Broadband Access Head End
- Wireless Communications
- Base Stations
- Point to point radios
- Broadband Access
- Test Equipment

Block Diagram



Parameter	Symbol	Min.	Тур	Max	Units
Output Frequency	f _o	5		27	MHz
Supply Voltage ¹ , Ordering Option	V _{DD}		+3.3 or +5.0		Vdc
Supply Current	I _{DD}			10	mA
Operating Temperature, Ordering Option	T _{OP}	0/55, -10/	/60, -20/70, -30/	80, -40/85	°C
Stability Over T _{or} Ordering Option		±0.5, ±1.0, ±.	5, ±2.0, ±2.5, ±3	.0, ±4.0, ±5.0	ppm
Initial Accuracy, "No Adjust" Option				±1.0	ppm
Power Supply Stability				±0.3	ppm
Load Stability				±0.2	ppm
Aging				±1.0	ppm/yr
Pull Range, ordering option	TPR	:	±5, ±8, ±10, ±12	2	ppm
Control Voltage to reach Pull Range		0.5		2.5	V
Control Voltage Impedance		1			Mohm
Output Level ² Output Logic High Output Logic Low Output Logic High Drive Output Logic Low Drive	V _{OH} V _{OL} I _{OH} I _{OL}	0.8*V _{DD}		0.1*V _{DD} -4	V V mA mA
Output Load				15	pF
Phase Noise, 10.000MHz 10Hz 100Hz 1kHz 10kHz 100kHz			-92 -116 -137 -149 -154		dBc/Hz
Enable Disable ³ , Output Enbaled Output Disabled	V _{IH} V _{IL}	0.3* _{VDD}		0.7*V _{DD}	
Start Up Time				2	ms

1. The V-701 power supply pin should be filtered, eg, a 0.1 and 0.01 uf capacitor

2. The Output is DC coupled

3. Output is Enabled if E/D is left open

Outline Drawing





Recommended Pad Layout



Pad Layout mm

Table 2. I	Table 2. Pinout									
Pin #	Symbol	Function								
1	V _c	TCXO Control Voltage or Ground								
2,3,4	NC	Make No Connection								
5	GND	Electrical and Lid Ground								
6	f _o	Output Frequency								
7,8	NC	Make No Connection								
9	E/D	Enable Disable								
10	V _{DD}	Supply Voltage								



Test Circuit



VCXO Function

VCXO Feature: The VT-701 can be ordered with a VCXO function for applications were it will be used in a PLL, or the output frequency needs fine tune or calibration adjustments. This is a high impedance input, 1Mohm, and can be driven with an op-amp or terminated with adjustable resistors etc. **Pin 1 should not be left floating on the VCXO optional device.**

"No Adjust" Option: In applications were the VT-701 will not be used in a PLL, or the output frequency does not need fine tune adjustments, the best device to use would be a VT-701-xxx-xxx0. By using the "no adjust" option, the circuit is simplified as Vc does not need to be adjusted or set to a predetermined voltage and pin 1 should be grounded (pin 1 can be left open but should not be set to a voltage such as an RF signal or power supply voltage.

Maximum Ratings

Absolute Maximum Ratings and Handling Precautions

Stresses in excess of the absolute maximum ratings can permanently damage the device. Functional operation is not implied or any other excess of conditions represented in the operational sections of this data sheet. Exposure to absolute maximum ratings for extended periods may adversely affect device reliability.

Although ESD protection circuitry has been designed into the VT-701, proper precautions should be taken when handling and mounting, VI employs a Human Body Model and Charged Device Model for ESD susceptibility testing and design evaluation. ESD thresholds are dependent on the circuit parameters used to define the model. Although no industry standard has been adopted for the CDM a standard resistance of 1.5kOhms and capacitance of 100pF is widely used and therefor can be used for comparison purposes.

Table 3. Maximum Ratings			
Parameter	Symbol	Rating	Unit
Storage Temperature	T _{STORE}	-55/125	°C
Supply Voltage	V _{DD}	6	V
Control Voltage	V _c	0/V _{DD}	V
ESD, Human Body Model		1500	V
ESD, Charged Device Model		1000	V

Table 4. Environmental Compliance					
Parameter	Condition				
Mechanical Shock	MIL-STD-883 Method 2002				
Mechanical Vibration	MIL-STD-883 Method 2007				
Temperature Cycle	MIL-STD-883 Method 1010				
Solderability	MIL-STD-883 Method 2003				
Fine and Gross Leak	MIL-STD-883 Method 1014				
Resistance to Solvents	MIL-STD-883 Method 2015				
Moisture Sensitivity Level	MSL1				
Contact Pads	Gold over Nickel				

IR Compliance

Suggested IR Profile

Devices are built using lead free epoxy and can be subjected to standard lead free IR reflow conditions shown in Table 5. Contact pads are gold over nickel and lower maximum temperatures can also be used, such as 220C.

Table 5. Reflow Profile		
Parameter	Symbol	Value
PreHeat Time	ts	200 sec Max
Ramp Up	R _{UP}	3°C/sec Max
Time above 217°C	tL	150 sec Max
Time to Peak Temperature	tAMB-P	480 sec Max
Time at 260°C	tP	30 sec Max
Time at 240°C	tP2	60 sec Max
Ramp down	R _{dn}	6°C/sec Max

Solderprofile:



Tape & Reel

Table 6.	Table 6. Tape and Reel Information											
Tape Dimensions (mm)			Reel Dimensions (mm)									
w	F	Do	Ро	P1	А	В	с	D	N	W1	W2	#/Reel
16	7.5	1.5	4	8	180	1.5	13	20.2	60	16.4	20.4	1000





Table 7. Standard Frequencies (MHz) Standard Frequencies									
5.000*	6.400*	8.192	10.000	12.500*	12.800	13.000*	16.384	19.200	20.000
19.440	19.800	20.000	24.000	25.000	26.000	27.000			

Ordering Information





* Add **_SNPBDIP** for tin lead solder dip Example: VT-701-EAG-206A-19M200000_SNPBDIP

Revision History

Revision Date	Approved	Description
August 10, 2018	FB	Rev 0.4: Updated logo and contact information, added "SNPBDIP" ordering option



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